# **OSRAM** KT DMLN31.13 **Datasheet**





#### SYNIOS® P2720

# **KT DMLN31.13**

This compact LED device is part of the SYNIOS P2720 family. Given the scalability of this product family, it provides full performance and flexibility with just one footprint. The KT DMLN31.13 product is meant to provide superior light quality in 1/4 mm<sup>2</sup> chip size class. The higher robustness and standardized footprint makes the LED flexible for any RGBW application.





#### **Applications**

- Access Control & Security
- Ambient Lighting
- Appliances & Tools
- Dynamic Signaling
- Factory Automation
- Home & Building Automation

- Material Processing
- Projection & Display
- Robotics
- Static Signaling
- Transportation

#### **Features**

- Package: SMD epoxy package

- Chip technology: UX:3

- Typ. Radiation: 120° (Lambertian emitter)

- Color: λ<sub>dom</sub> = 528 nm (• true green)

- Corrosion Robustness Class: 3B

- Qualifications: AEC-Q102 Qualified with RV-level 1

- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)





**Ordering Information** 

Туре Luminous Flux 1) Ordering Code

 $I_{\rm F} = 65 \, {\rm mA}$ 

 $\Phi_{V}$ 

15.9 ... 31.5 lm KT DMLN31.13-8F5H-36-L6E2 Q65112A3520



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
		max.	125 °C
Storage Temperature	T <sub>stg</sub>	min.	-40 °C
	- 0	max.	125 °C
Junction Temperature	$T_{j}$	max.	150 °C
Junction Temperature for short time applications*	T <sub>j</sub>	max.	175 °C
Forward current	I <sub>F</sub>	min.	5 mA
$T_S = 25  ^{\circ}C$		max.	300 mA
Surge current	I <sub>FS</sub>	max.	750 mA
$t \le 10 \ \mu s$ ; D = 0.005 ; $T_s = 25 \ ^{\circ}C$	10		
ESD withstand voltage	$V_{ESD}$		8 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	LSD		
Reverse current 2)	I <sub>R</sub>	max.	200 mA

<sup>\*</sup> The median lifetime (L70/B50) for Tj =  $175^{\circ}$ C is 100h.



#### **Characteristics**

 $I_F$  = 65 mA;  $T_S$  = 25 °C

Parameter	Symbol	Values	
Dominant Wavelength <sup>3)</sup> I <sub>F</sub> = 65 mA	$\lambda_{\sf dom}$	min. typ. max.	519 nm 528 nm 543 nm
Viewing angle at 50% $\rm I_{\rm v}$	2φ	typ.	120 °
Forward Voltage <sup>4)</sup> I <sub>F</sub> = 65 mA	$V_{F}$	min. typ. max.	2.10 V 2.55 V 3.50 V
Reverse voltage (ESD device)	$V_{\sf RESD}$	min.	45 V
Reverse voltage <sup>2)</sup> I <sub>R</sub> = 20 mA	$V_R$	max.	1.2 V
Real thermal resistance junction/solderpoint 5)	$R_{ ext{thJS real}}$	typ. max.	18 K / W 20 K / W
Electrical thermal resistance junction/solderpoint $^{5)}$ with efficiency $\eta_{\rm e}$ = 27 %	$R_{ ext{thJS elec.}}$	typ. max.	13 K / W 15 K / W



# **Brightness Groups**

Group	Luminous Flux <sup>1)</sup> I <sub>F</sub> = 65 mA	Luminous Flux $^{1)}$ $I_F = 65 \text{ mA}$	Luminous Intensity <sup>6)</sup> I <sub>F</sub> = 65 mA	
	min.	max.	typ.	
	$\Phi_{V}$	$\Phi_{V}$	I <sub>v</sub>	
8F	15.9 lm	18.0 lm	5.6 cd	
5G	18.0 lm	20.1 lm	6.3 cd	
6G	20.1 lm	22.4 lm	7.0 cd	
7G	22.4 lm	25.0 lm	7.8 cd	
8G	25.0 lm	28.0 lm	8.7 cd	
5H	28.0 lm	31.5 lm	9.8 cd	

# **Forward Voltage Groups**

Group	Forward Voltage <sup>4)</sup> I <sub>F</sub> = 65 mA min. V <sub>F</sub>	Forward Voltage <sup>4)</sup> I <sub>F</sub> = 65 mA max. V <sub>F</sub>	
L6	2.10 V	2.40 V	
S4	2.40 V	2.60 V	
W4	2.60 V	2.80 V	
24	2.80 V	3.00 V	
64	3.00 V	3.20 V	
A4	3.20 V	3.40 V	
E2	3.40 V	3.50 V	

# **Wavelength Groups**

Group	Dominant Wavelength 3)	Dominant Wavelength 3)
	I <sub>F</sub> = 65 mA	I <sub>F</sub> = 65 mA
	min.	max.
	$\lambda_{\sf dom}$	$\lambda_{dom}$
3	519 nm	525 nm
4	525 nm	531 nm
5	531 nm	537 nm
6	537 nm	543 nm



## **Group Name on Label**

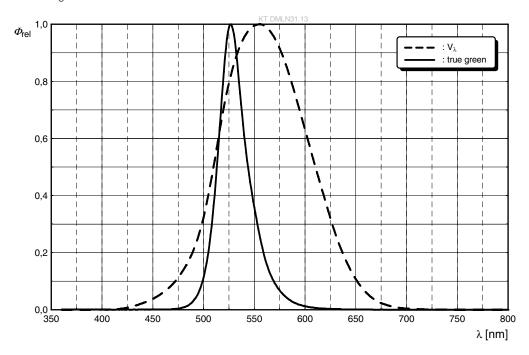
Example: 5G-3-24

Brightness	Wavelength	Forward Voltage	
5G	3	24	



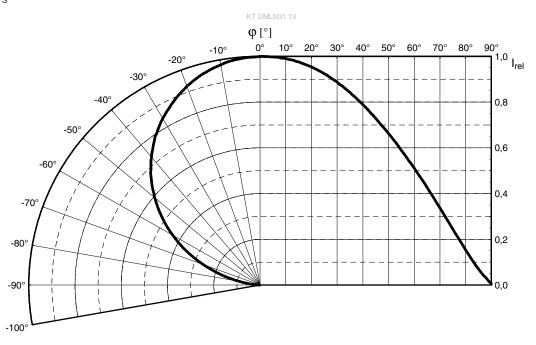
#### Relative Spectral Emission 6)

$$\Phi_{rel}$$
 = f ( $\lambda$ ); I<sub>F</sub> = 65 mA; T<sub>S</sub> = 25 °C



#### Radiation Characteristics 6)

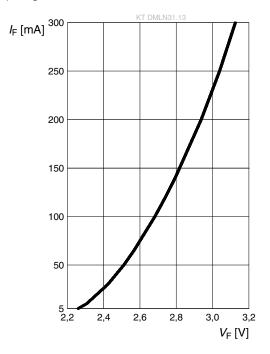
$$I_{rel} = f(\phi); T_S = 25 °C$$





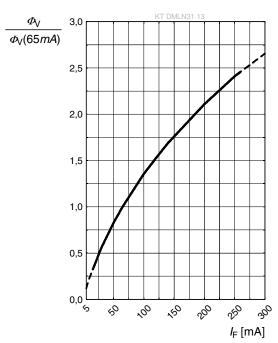
# Forward current 6), 7)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



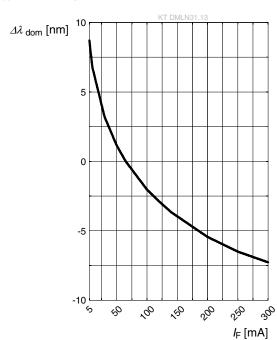
#### Relative Luminous Flux 6), 7)

$$\Phi_{v}/\Phi_{v}$$
(65 mA) = f(I<sub>F</sub>); T<sub>S</sub> = 25 °C



# Dominant Wavelength 6)

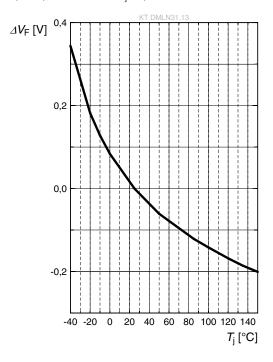
$$\Delta\lambda_{dom} = f(I_F); T_S = 25 \text{ }^{\circ}\text{C}$$





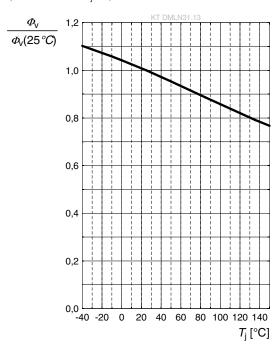
#### Forward Voltage 6)

$$\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 65 \ mA$$



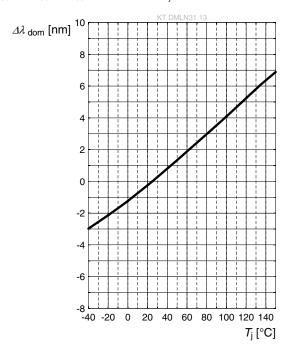
#### Relative Luminous Flux 6)

$$\Phi_{V}/\Phi_{V}(25 \text{ °C}) = f(T_{i}); I_{F} = 65 \text{ mA}$$



## Dominant Wavelength 6)

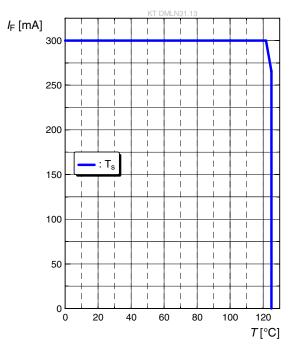
$$\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \text{ °C}) = f(T_j); I_F = 65 \text{ mA}$$





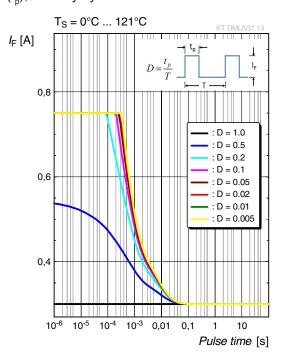
#### Max. Permissible Forward Current

 $I_{\scriptscriptstyle F} = f(T)$ 



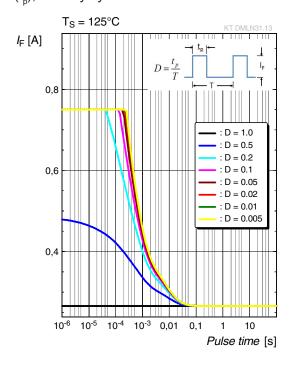
### Permissible Pulse Handling Capability

 $I_F = f(t_p)$ ; D: Duty cycle



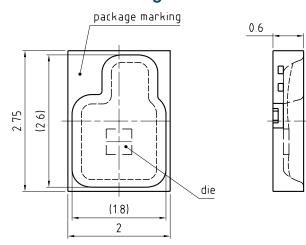
## Permissible Pulse Handling Capability

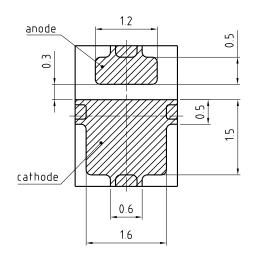
 $I_F = f(t_p)$ ; D: Duty cycle





#### **Dimensional Drawing** 8)





General tolerance ±0.1

Lead finish Au

C67062-A0116-A2-04

#### **Further Information:**

**Approximate Weight:** 12.0 mg

**Corrosion test:** Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter than IEC

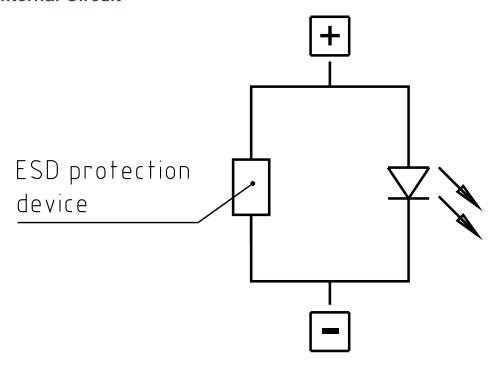
60068-2-43)

**ESD** advice: The device is protected by ESD device which is connected in parallel to the

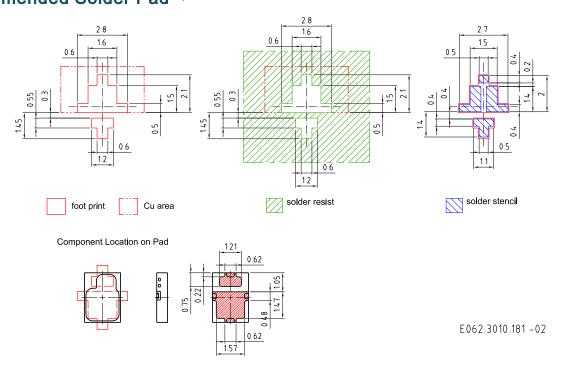
Chip.



#### **Electrical Internal Circuit**



#### Recommended Solder Pad 8)

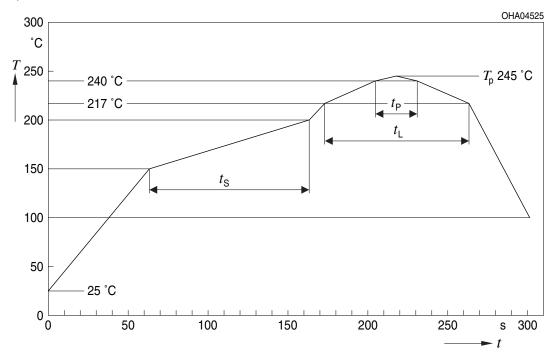


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



#### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



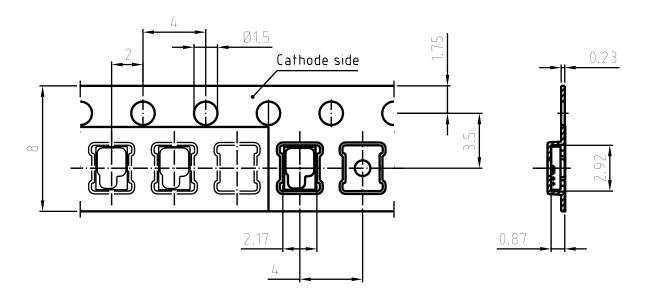
Profile Feature	Symbol	bol Pb-Free (SnAgCu) Assembly		Unit	
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)	'		2	3	K/s
25 °C to 150 °C					
Time t <sub>s</sub>	t <sub>s</sub>	60	100	120	S
$T_{Smin}$ to $T_{Smax}$					
Ramp-up rate to peak*)			2	3	K/s
$T_{Smax}$ to $T_{P}$					
Liquidus temperature	$T_{L}$		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T <sub>P</sub>		245	260	°C
Time within 5 °C of the specified peak	t <sub>P</sub>	10	20	30	S
temperature T <sub>P</sub> - 5 K					
Ramp-down rate*			3	6	K/s
T <sub>P</sub> to 100 °C					
Time				480	S
25 °C to T <sub>P</sub>					

All temperatures refer to the center of the package, measured on the top of the component

<sup>\*</sup> slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



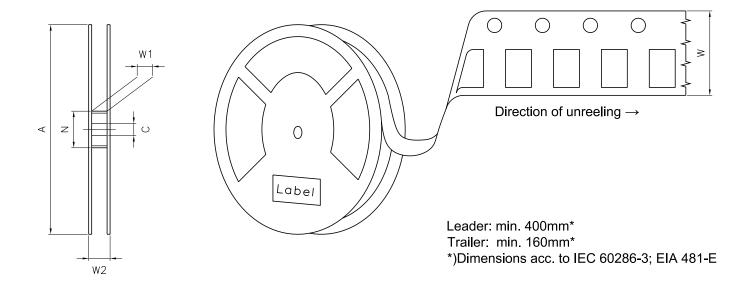
# Taping 8)



C67062-A0116-B9-04



## Tape and Reel 9)

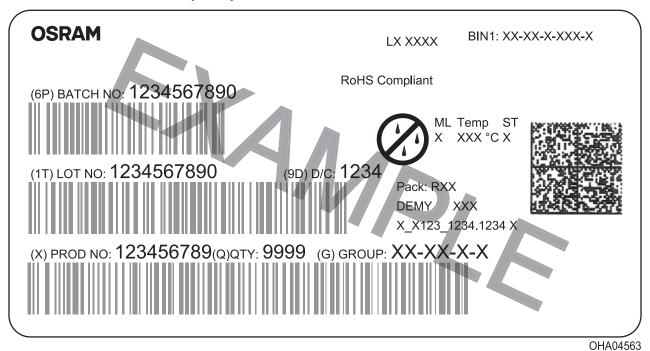


#### **Reel Dimensions**

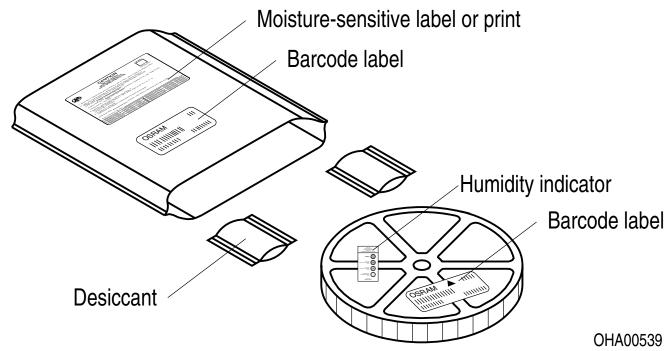
Α	W	$N_{\min}$	$W_1$	$W_{2 max}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	2000



#### **Barcode-Product-Label (BPL)**



## Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



#### **Notes**

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class moderate risk (exposure time 0.25 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



#### **Disclaimer**

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

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In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



#### Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) **Thermal Resistance:** Rth max is based on statistic values  $(6\sigma)$ .
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



## **Revision History**

Version	Date	Change
1.0	2018-11-28	Initial Version
1.1	2020-04-24	Schematic Transportation Box Dimensions of Transportation Box
1.2	2023-01-27	Dimensions of Transportation Box New Layout Characteristics Applications



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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XPGDRY-L1-0000-00401 XQEEPR-00-0000-00000901 XQEEPR-00-0000-000000A01 15335340AA350 XPCRDO-L1-R250-00701

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0000-00E02 15335338AA350 XPEROY-L1-R250-00903 XPEBRY-L1-R250-00R01 XPEEPR-L1-0000-00C01 MLESBL-A1-0000-00001

XPEBPA-L1-R250-00B01 XPERD-L1-R250-00802 XQEBLU-02-0000-00000305 XTEARY-00-0000-00000K03 XTEARY-02-0000-0000001